



SBSP52T1G Information



For Reference Only

Part Number SBSP52T1G

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN DARL 80V 1A SOT223

Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SBSP52T1G Specifications

Manufacturer Part Number	SBSP52T1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	80V
Vce Saturation (Max) @ Ib, Ic	1.3V @ 500μA, 500mA
Current - Collector Cutoff (Max)	10μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	2000 @ 500mA, 10V
Power - Max	800mW
Frequency - Transition	-
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	SOT-223 (TO-261)
	Report errors?

SBSP52T1G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SBSP52T1G Payment Methods





















SBSP52T1G Shipping Methods













If you have any question about SBSP52T1G, please do not hesitate to contact us!

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